



#### PNP SURFACE MOUNT TRANSISTOR

#### **Features**

- **Epitaxial Planar Die Construction**
- Complementary NPN Type Available (2DD2150)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

#### **Mechanical Data**

- Case: SOT89-3L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208

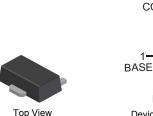
<u>3</u>E

2 C

1 B

- Marking Information: See Page 3
- Ordering Information: See Page 3,
- Weight: 0.072 grams (approximate)

С



TOP VIEW Pin Out Configuration

#### **Maximum Ratings** $@T_A = 25^{\circ}C$ unless otherwise specified

		· ·	
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-20	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-20	V
Emitter-Base Voltage	V <sub>EBO</sub>	-6	V
Peak Pulse Current	Ісм	-5	A
Continuous Collector Current	lc	-3	A

COLLECTOR 2,4

З

EMITTER

**Device Schematic** 

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ T <sub>A</sub> = 25°C	PD	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ T <sub>A</sub> = 25°C	R <sub>θJA</sub>	125	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

### Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Conditions
OFF CHARACTERISTICS (Note 4)						
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	-20		_	V	$I_{\rm C}$ = -50µA, $I_{\rm E}$ = 0
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	-20	—		V	I <sub>C</sub> = -1mA, I <sub>B</sub> = 0
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	-6	_		V	I <sub>E</sub> = -50μA, I <sub>C</sub> = 0
Collector Cut-Off Current	ICBO	_	—	-0.1	μA	$V_{CB} = -20V, I_E = 0$
Emitter Cut-Off Current	I <sub>EBO</sub>	_	_	-0.1	μA	$V_{EB} = -5V, I_{C} = 0$
ON CHARACTERISTICS (Note 4)						·
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	-0.18	-0.5	V	I <sub>C</sub> = -2A, I <sub>B</sub> = -0.1A
DC Current Gain	h <sub>FE</sub>	180	_	390	_	$V_{CE}$ = -2V, $I_{C}$ = -0.1A
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C <sub>obo</sub>		28		pF	$V_{CB}$ = -10V, $I_E$ = 0, f = 1MHz
Current Gain-Bandwidth Product	f⊤		220		MHz	V <sub>CE</sub> = -2V, I <sub>E</sub> = 0.1A, f = 100MHz

Notes: No purposefully added lead. 1.

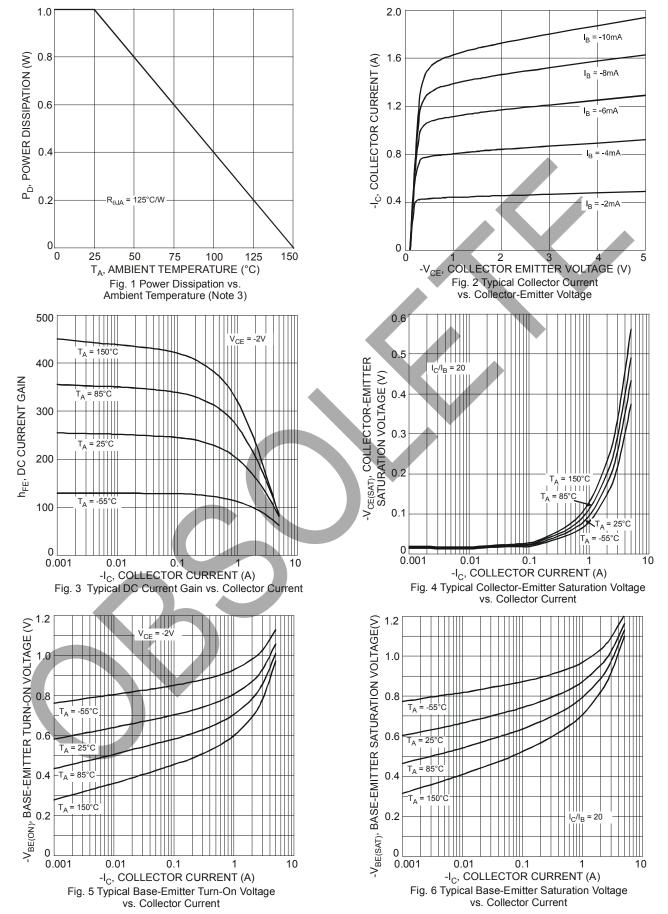
2.

Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php. Device mounted on FR-4 PCB; pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our 3. website at http://www.diodes.com/datasheets/ap02001.pdf.

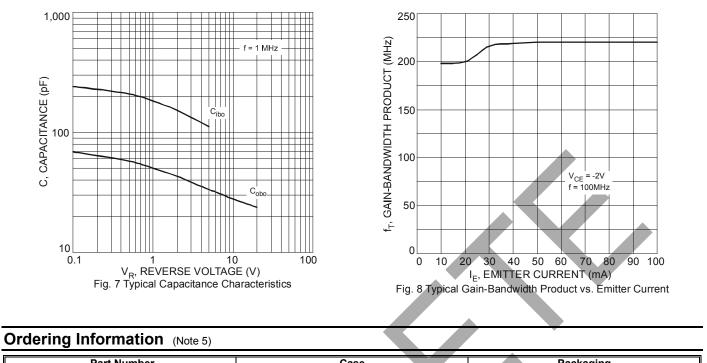
4. Measured under pulsed conditions. Pulse width =  $300\mu s$ . Duty cycle  $\leq 2\%$ .



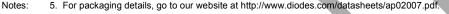
# 2DB1424R



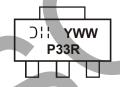




	Part Number	Case	Packaging	
	2DB1424R-13	SOT89-3L	2500/Tape & Reel	
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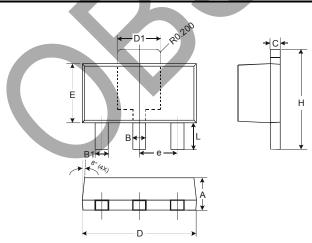






P33R = Product Type Marking Code YWW = Date Code Marking Y = Last digit of year (ex: 7 = 2007) WW = Week code 01 - 52

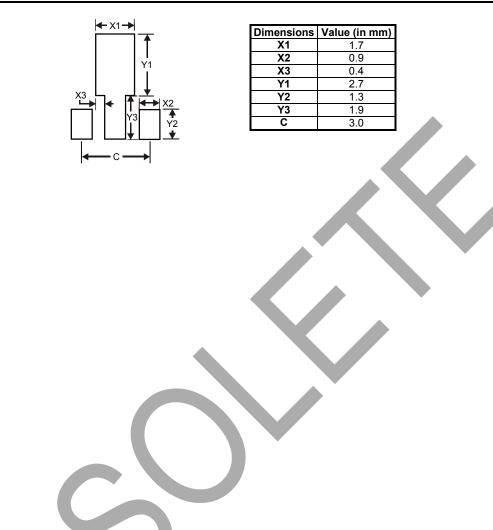
# **Package Outline Dimensions**



SOT89-3L					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.45	0.55	0.50		
B1	0.37	0.47	0.42		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.50	1.70	1.60		
Е	2.40	2.60	2.50		
е			1.50		
Н	3.95	4.25	4.10		
L	0.90	1.20	1.05		
All Dimensions in mm					



# **Suggested Pad Layout**





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